

# Peculiar magnetic phase in antiferromagnet MnTe

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Antiferromagnets get increasing attention nowadays as their magnetic state is coupled to its resistivity state and importantly, it may be influenced by electric current [1, 2]. A new puzzling chapter has opened with the developments of topology - in particular, some antiferromagnets have been predicted to exhibit exceptional properties, induced just by the crystal symmetry and not by relativistic effects [3], e.g. existence of anomalous Hall effect (even in a magnetically-compensated system). Recently, experimental evidence was made for RuO<sub>2</sub> [4] and thin MnTe films [5].

Hexagonal MnTe is a semiconductor with a moderate band gap (about 1.3 eV), room temperature resistivity of about a few  $\Omega\cdot\text{cm}$  and the Néel temperature  $T_N$  of 308 K. We performed structural, optical, transport and magnetic studies of state-of-the-art bulk samples in wide temperature and magnetic field range. We have traced the Hall voltage behaviour revealing nonlinearities in  $\rho_{xy}(B)$  dependence. The observed data were fitted in multi-carrier model, providing two hole and one electron channel. The results will be referred to the recent band structure calculations [6]. Moreover, similarly to [5] we have observed a clear hysteresis loop in  $\rho_{xy}(B)$  seen exclusively below  $T_N$ . However, the loop is flipped with respect to the one observed in epitaxial MnTe [5]. The presence of hysteresis in the Hall resistivity coincides with a weak ferromagnetic signal, resolved in SQUID magnetometry. A discussion about the origin of the observed phenomena will be provided.

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